



SSCE5V032N1

Ultra-low Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

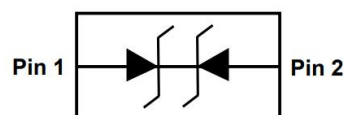
● Description

The SSCE5V032N1 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The SSCE5V032N1 has an ultra-low capacitance with a typical value at 0.2pF, and complies with the IEC 61000-4-2 (ESD) with $\pm 20\text{kV}$ air and $\pm 20\text{kV}$ contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, USB 3.0 super speed, VGA, DVI, HDMI, SDI and other high speed line applications.

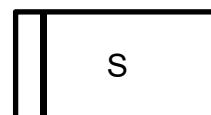
● Feature

- ✧ 100W peak pulse power ($t_P = 8/20\mu\text{s}$)
- ✧ DFN1006-2L Package
- ✧ Working voltage: 5V
- ✧ Low clamping voltage
- ✧ Low capacitance
- ✧ Low leakage current
- ✧ RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD) $\pm 20\text{kV}$ (air), $\pm 20\text{kV}$ (contact)

● PIN configuration



Top view



Marking

● Applications

- ✧ DVI & HDMI Port Protection
- ✧ USB 2.0 and USB 3.0
- ✧ SATA and eSATA
- ✧ Serial and Parallel Ports
- ✧ Projection TV
- ✧ Notebooks, Desktops, Servers

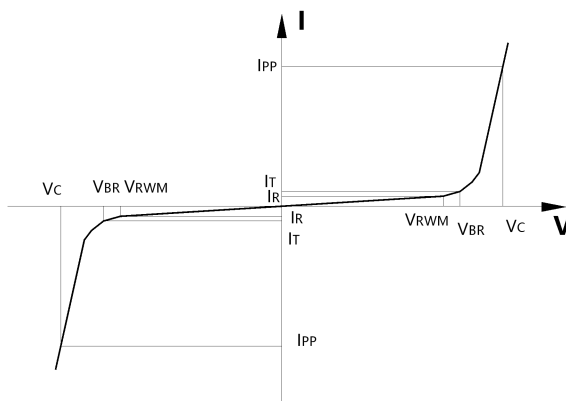
● Mechanical data

- ✧ Lead finish: 100% matte Sn(Tin)
- ✧ Mounting position: Any
- ✧ Qualified max reflow temperature: 260°C
- ✧ Device meets MSL 1 requirements
- ✧ Pure tin plating: $7 \sim 17 \mu\text{m}$
- ✧ Pin flatness: $\leq 3\text{mil}$



● Electronic Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance



● Absolute maximum rating @ $T_A=25^{\circ}\text{C}$

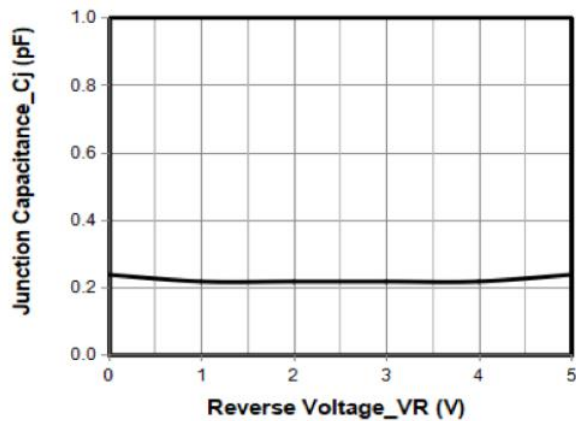
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	P_{PP}	100	W
Peak Pulse Current (8/20 μs)	I_{PP}	4	A
ESD Rating per IEC61000-4-2:			
Contact	V_{ESD}	20	kV
Air		20	
Storage Temperature	T_{STG}	-55/+150	$^{\circ}\text{C}$
Operating Temperature	T_J	-55/+125	$^{\circ}\text{C}$

● Electrical Characteristics @ $T_A=25^{\circ}\text{C}$

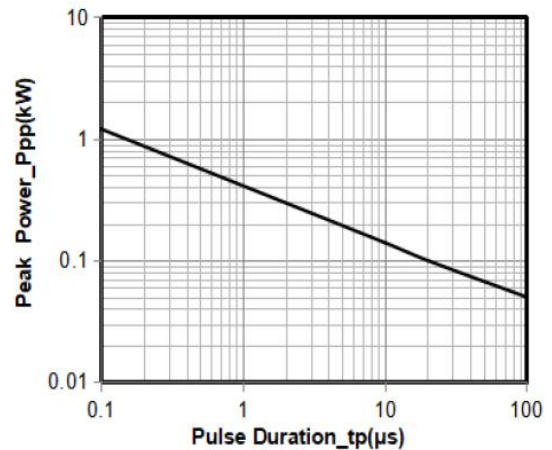
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Working Voltage	V_{RWM}				5	V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	6		9	V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$			1	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_P = 8/20\mu\text{s}$		12		V
Clamping Voltage	V_C	$I_{PP} = 4\text{A}$, $t_P = 8/20\mu\text{s}$			25	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$		0.2	0.4	pF



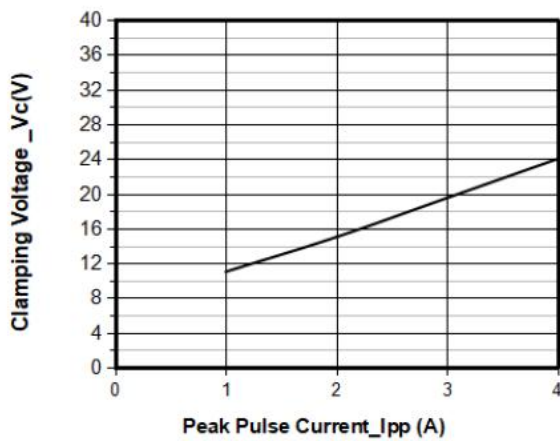
● Typical Performance Characteristics



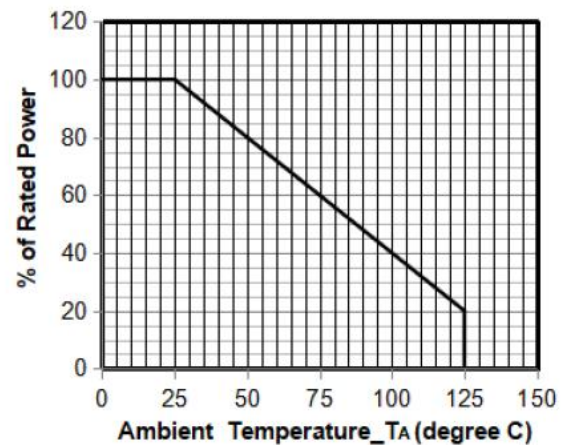
Junction Capacitance vs. Reverse Voltage



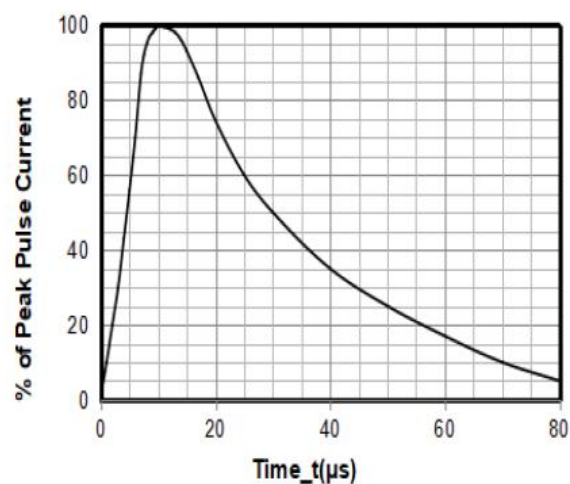
Peak Pulse Power vs. Pulse Time



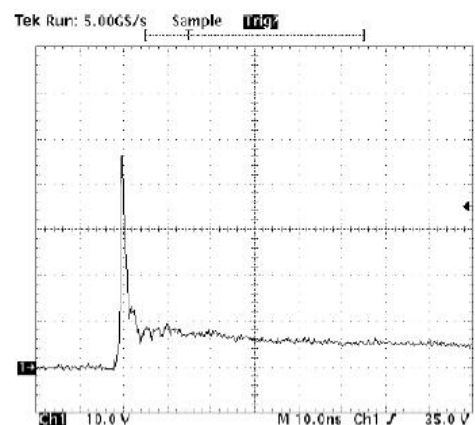
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



8 X 20 μ s Pulse Waveform



Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2



● Package Information

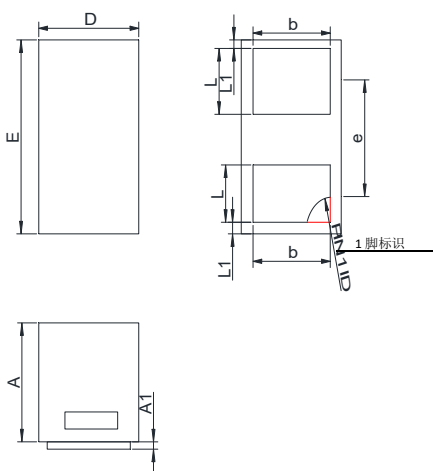
Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCE5V032N1	DFN1006-2L	10000	7 Inch

Mechanical Data

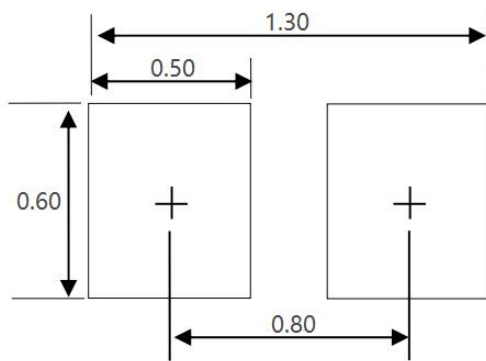
Case:DFN1006-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters	
	Min	Max
A	0.43	0.55
A1	0.00	0.05
D	0.55	0.65
E	0.95	1.05
b	0.45	0.60
e	0.65TYP	
L	0.2	0.3
L1	0.05REF	

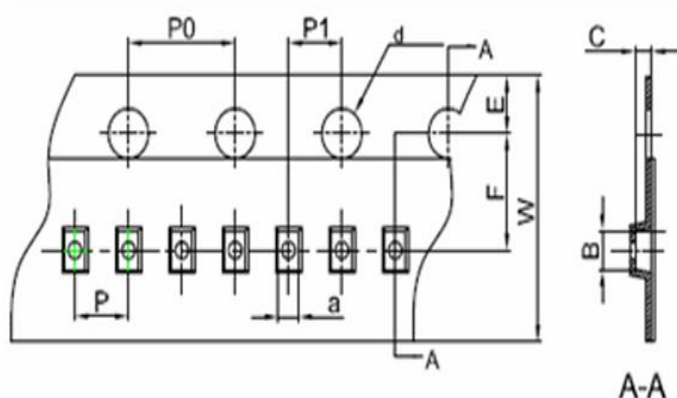
Recommended Pad outline



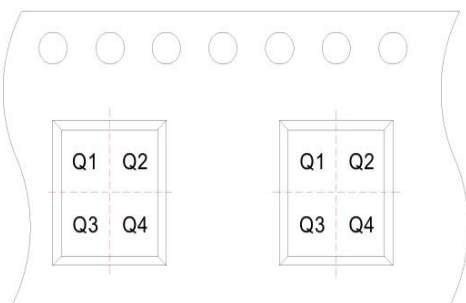
Unit:mm



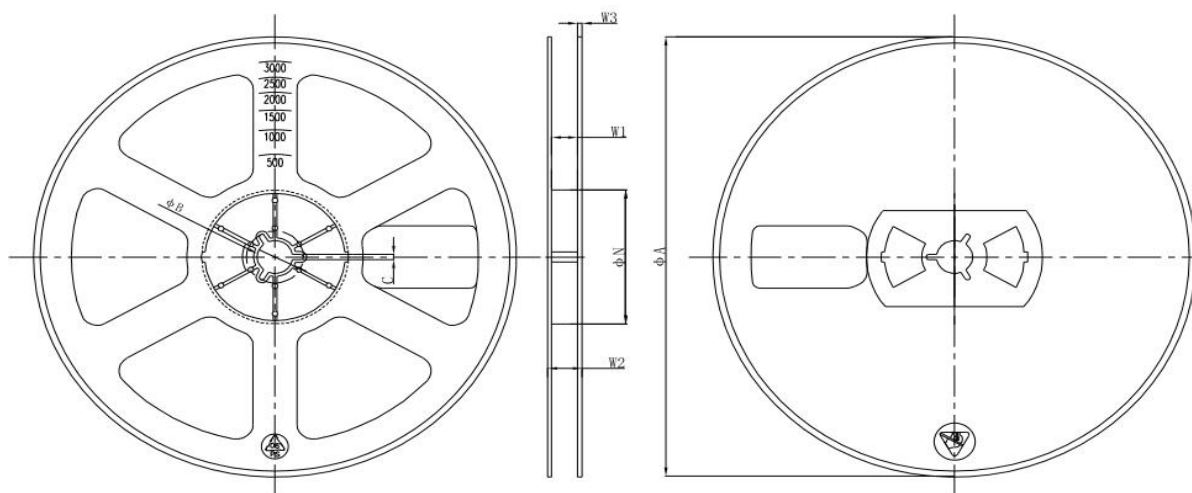
● Type and Reel Information-DFN1006-2L



DIM	Millimeters
	Typ
a	0.68
B	1.14
C	0.58
d	Φ 1.55
E	1.75
F	3.50
P0	4.00
P	2.00
P1	2.00
W	8.00



Pin 1 Quadrant: Q1&Q2



ΦA	ΦN	ΦB	C	W1	W2	W3
178mm	54mm	13.2mm	2.2mm	9.5mm	13 _{max} mm	1.4mm



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